

BT132-600D 4Q Triac

Rev.03 - 26 July 2023

Product data sheet

1. General description

Planar passivated very sensitive gate four quadrant triac in a TO92 plastic package intended for use in general purpose bidirectional switching and phase control applications. This very sensitive gate "series D" triac is intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

2. Features and benefits

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- High blocking voltage capability
- Very sensitive gate
- Planar passivated for voltage ruggedness and reliability
- Triggering in all four quadrants
- Direct interfacing to logic level ICs
- Direct interfacing to low power gate drivers and microcontrollers
- · Enhanced current surge capability

3. Applications

- Battery powered applications
- General purpose switching and phase control
- Air conditioner indoor fan control

4. Quick reference data

Table 1	. Quic	k reference	data
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Symbol	Parameter	Conditions		Va	lues		Unit
Absolute	maximum rating						
V _{drm}	repetitive peak off-state voltage			6	00		V
T(RMS)	RMS on-state current	full sine wave; T _{lead} ≤ 51 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	1			A	
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4;</u> <u>Fig. 5</u>	16			A	
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	17.5			A	
Tj	junction temperature		125			°C	
Symbol	Parameter	Conditions	N	lin	Тур	Max	Unit
Static ch	aracteristics						_
I _{GT}	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; <u>Fig. 7</u>	-		2	5	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; Fig. 7	-		2.5	5	mA
		$V_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}; \text{ T2- G-};$ $T_{j} = 25 \text{ °C}; \text{ Fig. 7}$	-		2.5	5	mA
		V_{D} = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 7</u>	-		5	10	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-		1.2	10	mA
V _T	on-state voltage	I _T = 5 A; T _i = 25 °C; <u>Fig. 10</u>	-		1.4	1.7	V

4Q Triac

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Dynamic characteristics							
dV _D /dt	rate of rise of off-state voltage			-	5	-	V/µs

5. Pinning information

Table 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol			
1	T2	main terminal 2		Ν			
2	G	gate					
3	T1	main terminal 1	ЦЦ ЦЦЦ 321 то-92 (SOT54)	sym051			

6. Ordering information

Table 3. Ordering information								
Type number	Package	Orderable part number	Packing	Small packing	Package	Package		
	Name		method	quantity	version	issue date		
BT132-600D	TO92	BT132-600D,412	Bulk	1000	SOT54	14-Nov-2013		
BT132-600D	TO92	BT132-600D,116	Reel	2000	SOT54 wide pitch	14-Nov-2013		

7. Marking

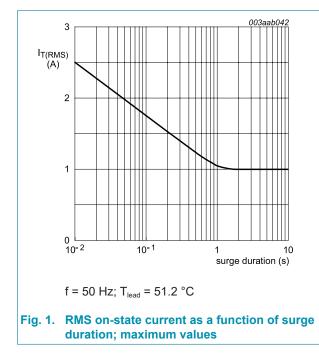
Fable 4. Marking codes	
Type number	Marking codes
BT132-600D	132-6D

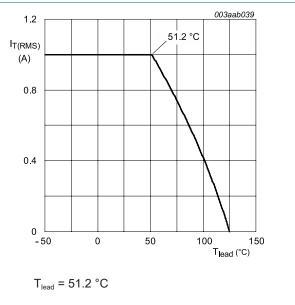
8. Limiting values

Table 5. Limiting values

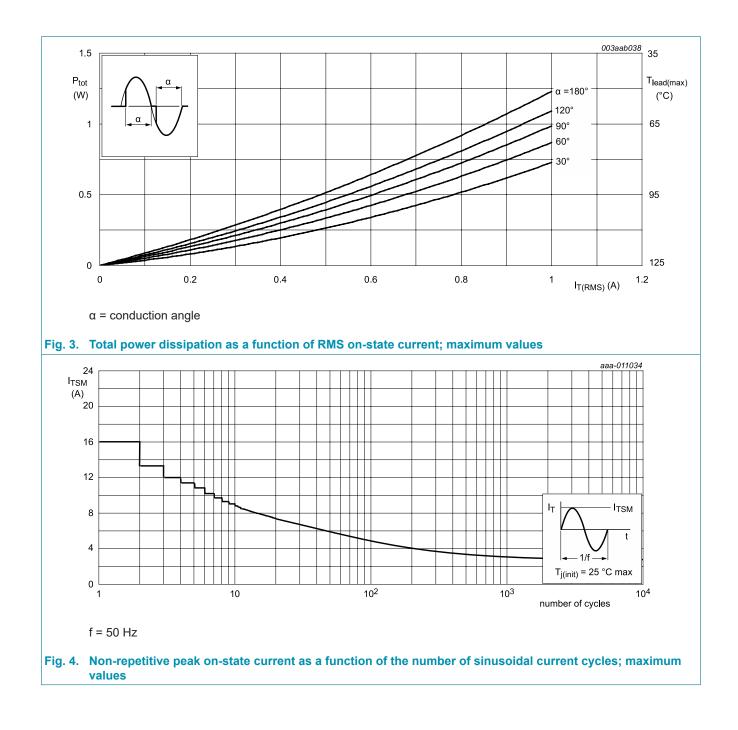
In accordance with the Absolute Maximum Rating System (IEC 60134).

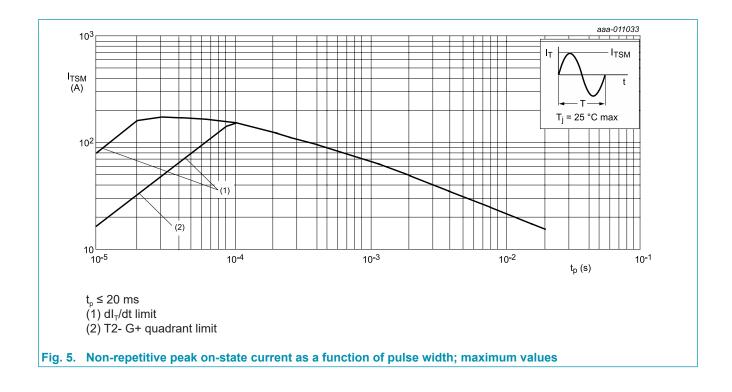
Symbol	Parameter	Conditions	Values	Unit
V_{DRM}	repetitive peak off-state voltage		600	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{lead} ≤ 51 °C; <u>Fig 1</u> ; <u>Fig 2</u> ; <u>Fig 3</u>	1	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig 4; Fig 5	16	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	17.5	A
l ² t	I ² t for fusing	t _p = 10 ms; SIN	1.28	A ² s
dl _T /dt	rate of rise of on-state current	I _G = 10 mA	50	A/µs
		I _G = 10 mA	50	A/µs
		I _G = 10 mA	50	A/µs
		I _G = 20 mA	10	A/µs
I _{GM}	peak gate current		2	А
P _{GM}	peak gate power		5	W
P _{G(AV)}	average gate power	over any 20 ms period	0.5	W
T _{stg}	storage temperature		-40 to 150	°C
Tj	junction temperature		125	°C





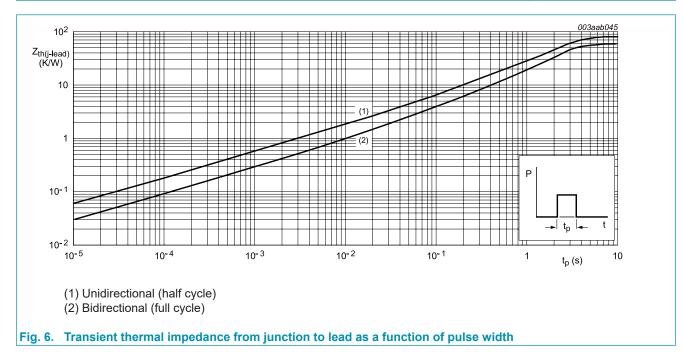






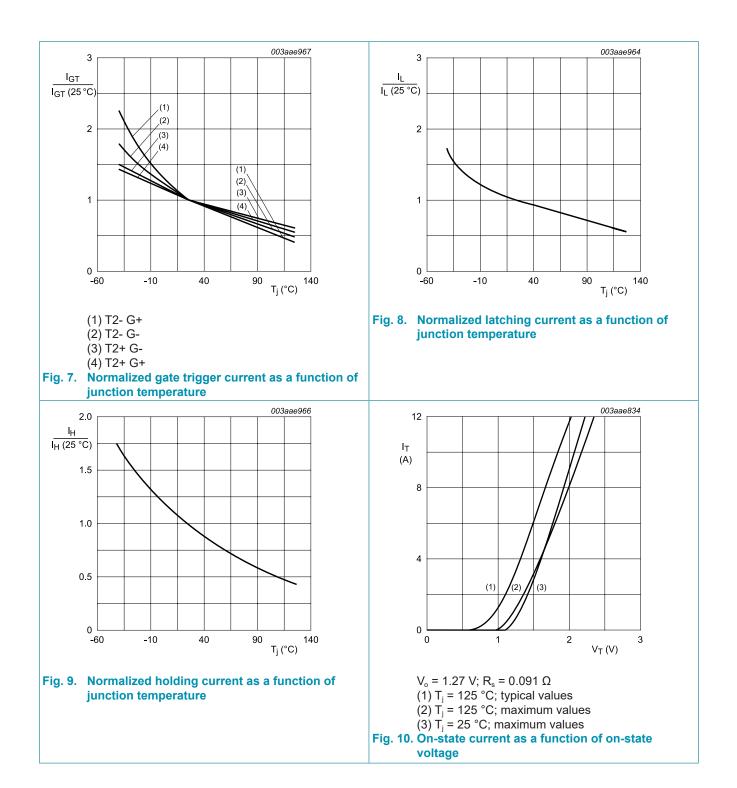
9. Thermal characteristics

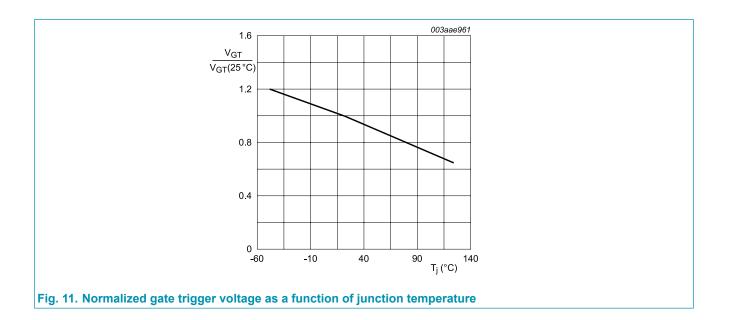
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
fi	thermal resistance from junction to lead	full cycle; <u>Fig 6</u>	-	-	60	K/W
		half cycle; <u>Fig 6</u>	-	-	80	K/W
$R_{\text{th}(j\text{-}a)}$	thermal resistance from junction to ambient free air	printed circuit mounted: lead length = 4 mm	-	150	-	K/W



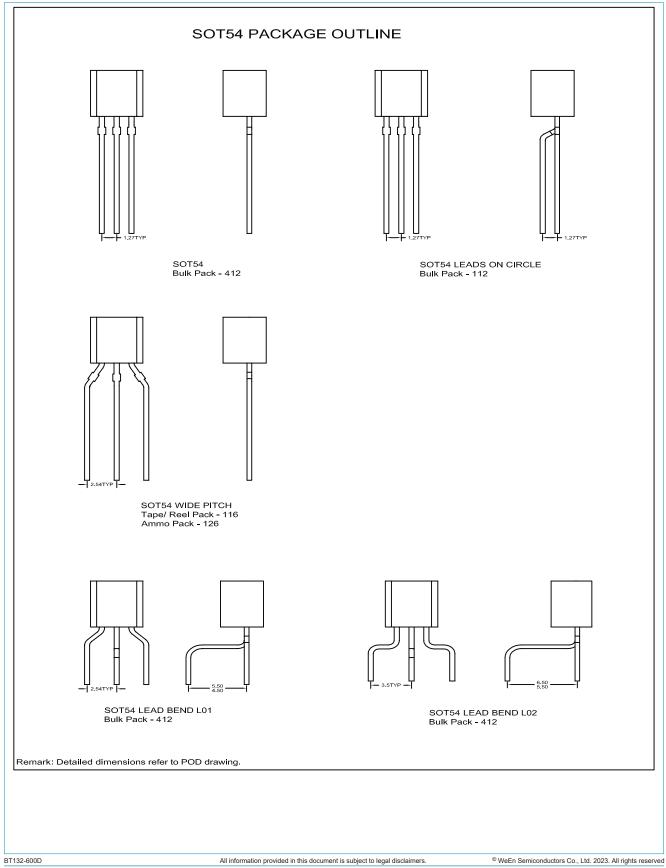
10. Characteristics

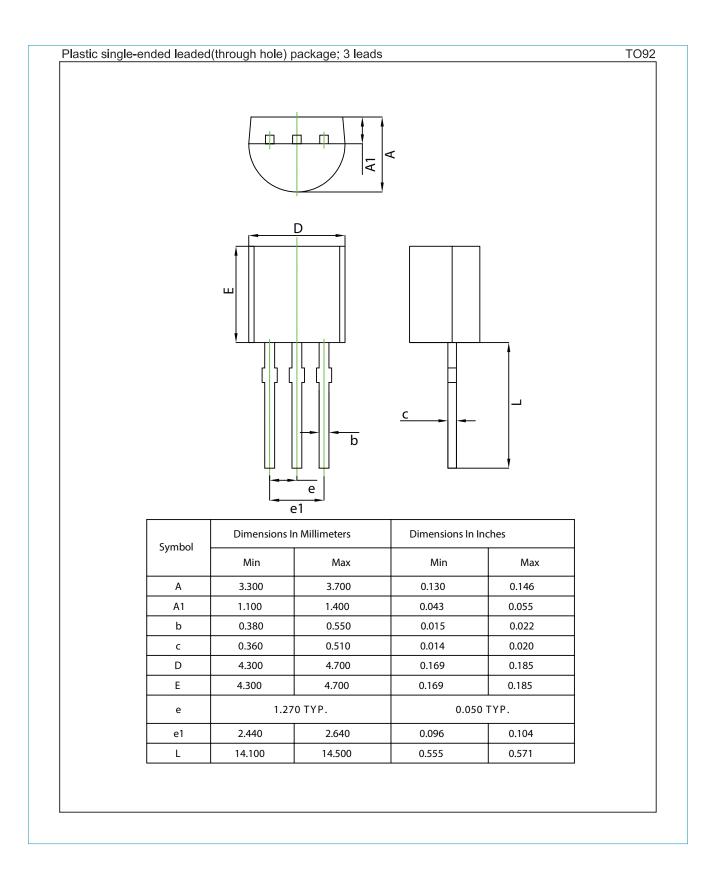
Symbol	Parameter	Conditions	M	lin	Тур	Max	Unit
Static cha	racteristics						
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u>	-		2	5	mA
		V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u>	-		2.5	5	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u>	-		2.5	5	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G+};$ T _j = 25 °C; <u>Fig. 7</u>	-		5	10	mA
I,	latching current	$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G+};$ $\text{T}_j = 25 \text{ °C}; \text{ Fig. 8}$	-		1.6	10	mA
		V_{D} = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 8</u>	-		4.5	15	mA
		V _D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 8</u>	-		1.2	10	mA
		$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G+};$ T _j = 25 °C; <u>Fig. 8</u>	-		2.2	15	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-		1.2	10	mA
V _T	on-state voltage	I _T = 5 A; T _j = 25 °C; <u>Fig. 10</u>	-		1.4	1.7	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 11</u>	-		0.7	1.5	V
		V _D = 400 V; I _T = 0.1 A; T _j = 125 °C	0.	.25	0.4	-	V
I _D	off-state current	V _D = 600 V; T _j = 125 °C	-		0.1	0.5	mA
Dynamic	characteristics		I				
dV _D /dt	rate of rise of off-state voltage		-		5	-	V/µs
t _{gt}	gate-controlled turn-on time	I_{TM} = 6 A; V_{D} = 600 V; I_{G} = 0.1 A; $dI_{G}/$ dt = 5 A/ μs	-		2	-	μs
	1	1	1				





11. Package outline





12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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